



SGM8250-1/SGM8250-2

High Voltage, Micro-Power, Zero-Drift, CMOS Operational Amplifiers

GENERAL DESCRIPTION

The single SGM8250-1 and dual SGM8250-2 are micro-power, high voltage, high precision CMOS operational amplifiers. These devices can operate from 3V to 24V single supply or from $\pm 1.5V$ to $\pm 12V$ dual power supplies, and consume only 50 μA quiescent current per amplifier. The SGM8250-1/2 support rail-to-rail input and output operation. The input common mode voltage range is from $(-V_S) - 0.1V$ to $(+V_S) + 0.1V$, and the output range is from $(-V_S) + 0.037V$ to $(+V_S) - 0.065V$.

The SGM8250-1/2 have high impedance inputs and zero-drift 50 μV (MAX) offset voltage. These specifications make SGM8250-1/2 appropriate for a wide range of applications requiring high precision.

The SGM8250-1 is available in Green SOT-23-5, SC70-5 and SOIC-8 packages. The SGM8250-2 is available in Green TDFN-3 $\times$ 3-8L and SOIC-8 packages. They are specified over $-40^{\circ}C$ to $+125^{\circ}C$ temperature range.

FEATURES

- **Low Input Offset Voltage:** 50 μV (MAX)
- **Low Noise:** 0.85 μV_{P-P} at 0.1Hz to 10Hz
- **Quiescent Current:** 50 μA /Amplifier (TYP)
- **Rail-to-Rail Input and Output**
- **Support Single or Dual Power Supplies:**
3V to 24V or $\pm 1.5V$ to $\pm 12V$
- **$-40^{\circ}C$ to $+125^{\circ}C$ Operating Temperature Range**
- **Small Packaging:**
SGM8250-1 Available in Green SOT-23-5, SC70-5 and SOIC-8 Packages
SGM8250-2 Available in Green TDFN-3 $\times$ 3-8L and SOIC-8 Packages

APPLICATIONS

Industrial Equipment
Battery-Powered Equipment
Sensor Signal Conditioning

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM8250-1	SOT-23-5	-40°C to +125°C	SGM8250-1XN5G/TR	GSCXX	Tape and Reel, 3000
	SC70-5	-40°C to +125°C	SGM8250-1XC5G/TR	GS3XX	Tape and Reel, 3000
	SOIC-8	-40°C to +125°C	SGM8250-1XS8G/TR	SGM 82501XS8 XXXXX	Tape and Reel, 4000
SGM8250-2	TDFN-3×3-8L	-40°C to +125°C	SGM8250-2XTDB8G/TR	SGM 82502DB XXXXX	Tape and Reel, 4000
	SOIC-8	-40°C to +125°C	SGM8250-2XS8G/TR	SGM 82502XS8 XXXXX	Tape and Reel, 4000

MARKING INFORMATION

NOTE: XX = Date Code. XXXXX = Date Code and Vendor Code.

SOT-23-5/SC70-5

YYY X X

Date Code - Month
Date Code - Year
Serial Number

SOIC-8/TDFN-3×3-8L

XXXXX

Vendor Code
Date Code - Week
Date Code - Year

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage 26.4V
 Input Common Mode Voltage Range
 (-V_S) - 0.3V to (+V_S) + 0.3V
 Junction Temperature +150°C
 Storage Temperature Range -65°C to +150°C
 Lead Temperature (Soldering, 10s) +260°C
 ESD Susceptibility
 HBM 8000V
 MM 250V
 CDM 1000V

RECOMMENDED OPERATING CONDITIONS

Specified Voltage Range 3V to 24V
 Operating Temperature Range -40°C to +125°C

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to

absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

ESD SENSITIVITY CAUTION

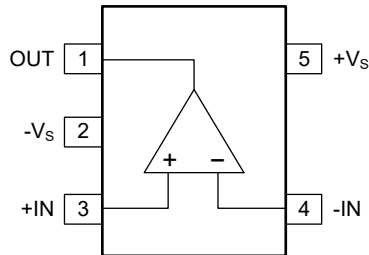
This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

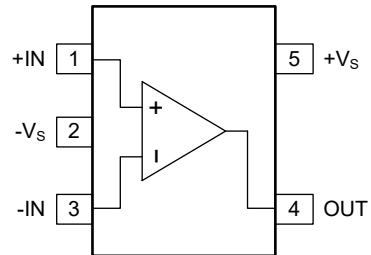
PIN CONFIGURATIONS

SGM8250-1 (TOP VIEW)



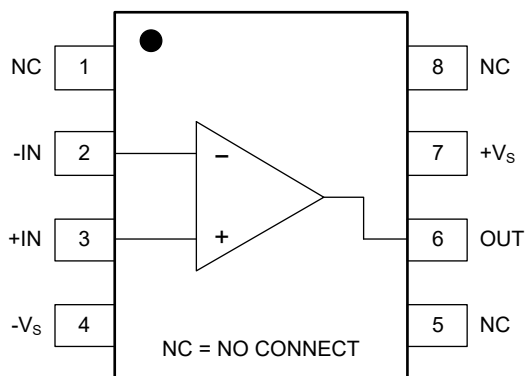
SOT-23-5

SGM8250-1 (TOP VIEW)



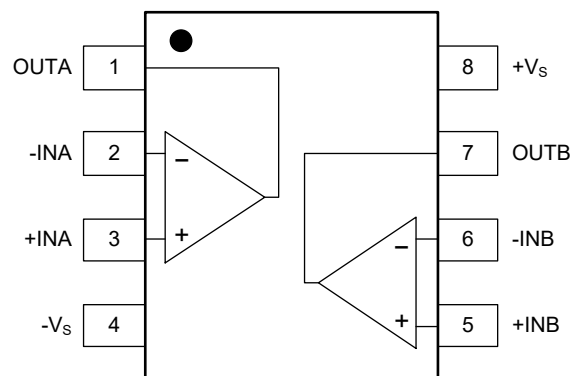
SC70-5

SGM8250-1 (TOP VIEW)



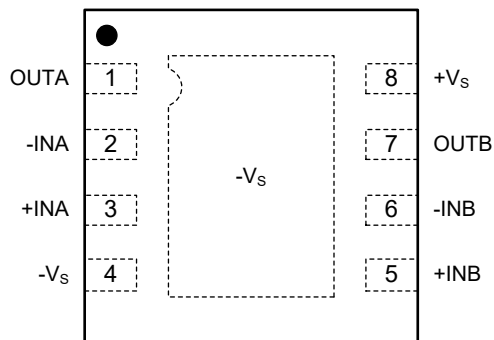
SOIC-8

SGM8250-2 (TOP VIEW)



SOIC-8

SGM8250-2 (TOP VIEW)



TDFN-3x3-8L

ELECTRICAL CHARACTERISTICS

($+V_S = 5V$, $-V_S = 0V$, $V_{CM} = +V_S/2$, $V_{OUT} = +V_S/2$ and $R_L = 10k\Omega$ to $+V_S/2$, Full = $-40^\circ C$ to $+125^\circ C$, typical values are at $T_A = +25^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
Input Characteristics							
Input Offset Voltage	V _{OS}		+25°C		10	50	μV
			Full			90	
Input Offset Voltage Drift	ΔV _{OS} /ΔT		Full		0.11		μV/°C
Input Bias Current	I _B		+25°C		60		pA
Input Common Mode Voltage Range	V _{CM}		Full	(-V _S) - 0.1		(+V _S) + 0.1	V
Common Mode Rejection Ratio	CMRR	(-V _S) - 0.1V < V _{CM} < (+V _S) + 0.1V	+25°C	95	112		dB
			Full	92			
Open-Loop Voltage Gain	A _{OL}	(-V _S) + 0.1V < V _{OUT} < (+V _S) - 0.1V	+25°C	108	131		dB
			Full	105			
Output Characteristics							
Output Voltage Swing from Rail	V _{OH}		+25°C		14	25	mV
			Full			30	
	V _{OL}		+25°C		8	16	
			Full			20	
Output Short-Circuit Current	I _{SC}		+25°C		±17		mA
Power Supply							
Operating Voltage Range	V _S		Full	3		24	V
Quiescent Current/Amplifier	I _Q	I _{OUT} = 0mA	+25°C		45	60	μA
			Full			80	
Power Supply Rejection Ratio	PSRR	V _S = 3V to 24V	+25°C	116	142		dB
			Full	113			
Dynamic Performance							
Gain-Bandwidth Product	GBP	G = +100, C _L = 100pF	+25°C		350		kHz
Slew Rate	SR	G = +1, V _{OUT} = 2V _{P-P} , C _L = 100pF	+25°C		0.1		V/μs
Turn-On Time			+25°C		0.75		ms
Noise							
Input Voltage Noise		f = 0.1Hz to 10Hz	+25°C		0.85		μV _{P-P}
Input Voltage Noise Density	e _n	f = 1kHz	+25°C		40		nV/√Hz

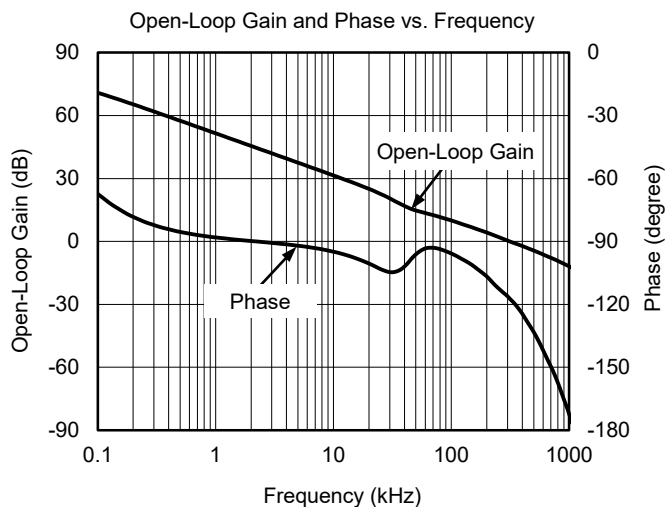
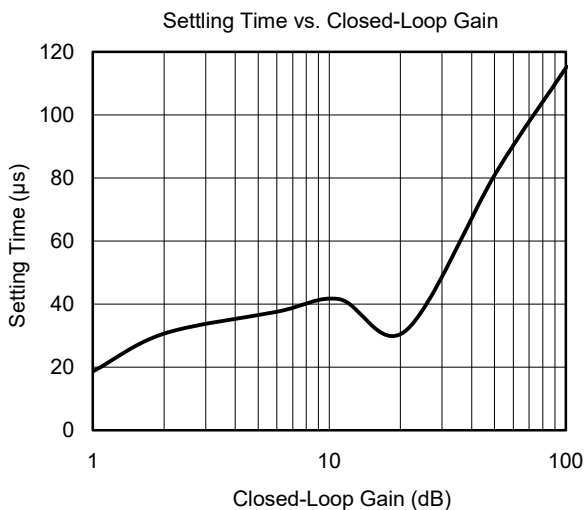
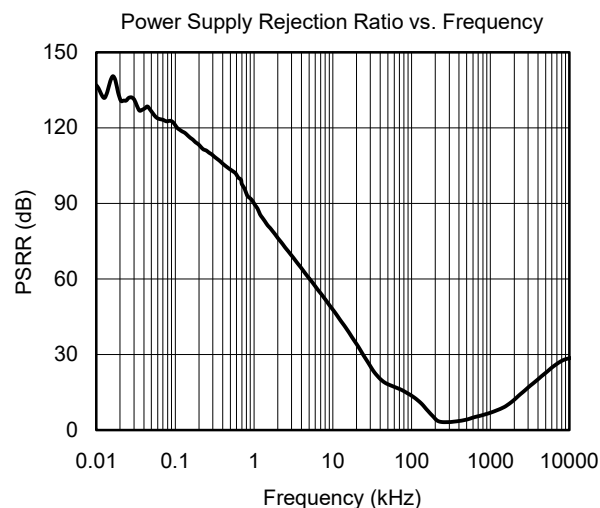
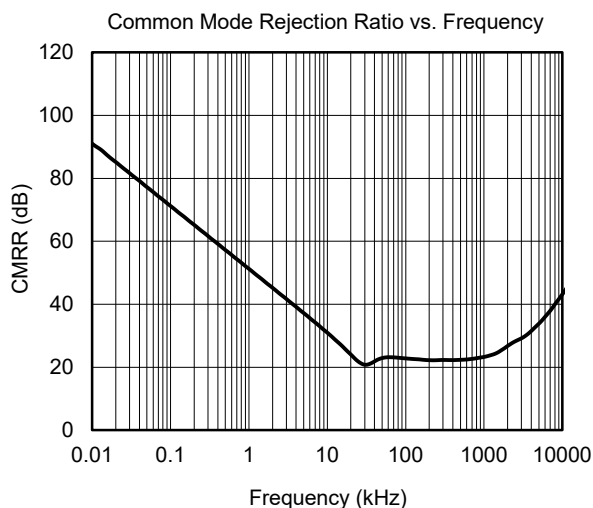
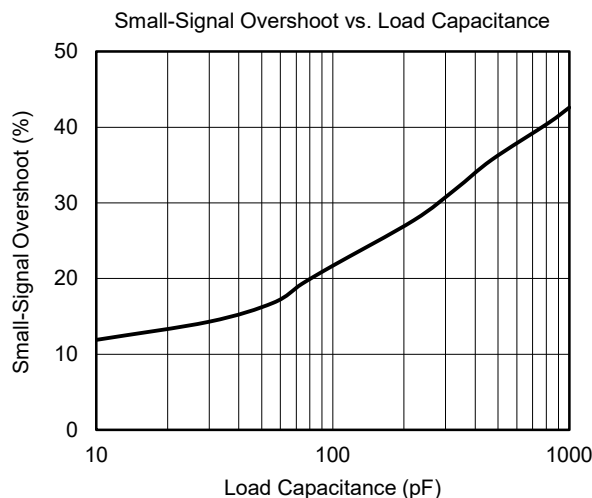
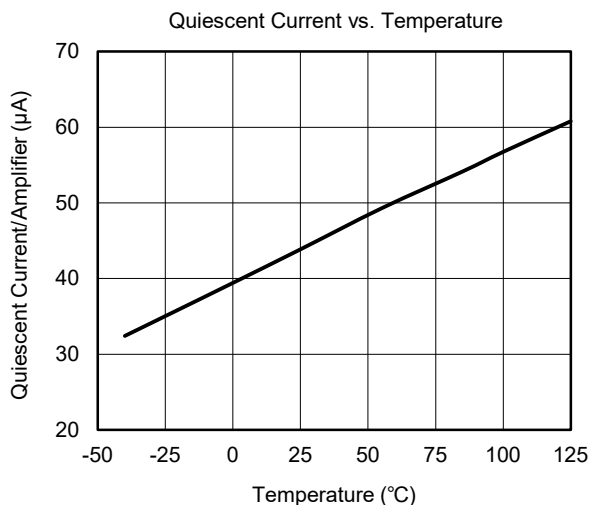
ELECTRICAL CHARACTERISTICS (continued)

($+V_S = 24V$, $-V_S = 0V$, $V_{CM} = +V_S/2$, $V_{OUT} = +V_S/2$ and $R_L = 10k\Omega$ to $+V_S/2$, Full = $-40^\circ C$ to $+125^\circ C$, typical values are at $T_A = +25^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
Input Characteristics							
Input Offset Voltage	V _{OS}		+25°C		10	50	μV
			Full			90	
Input Offset Voltage Drift	ΔV _{OS} /ΔT		Full		0.11		μV/°C
Input Bias Current	I _B		+25°C		80	850	pA
Input Common Mode Voltage Range	V _{CM}		Full	(-V _S) - 0.1		(+V _S) + 0.1	V
Common Mode Rejection Ratio	CMRR	(-V _S) - 0.1V < V _{CM} < (+V _S) + 0.1V	+25°C	112	130		dB
			Full	107			
Open-Loop Voltage Gain	A _{OL}	(-V _S) + 0.1V < V _{OUT} < (+V _S) - 0.1V	+25°C	120	145		dB
			Full	110			
Output Characteristics							
Output Voltage Swing from Rail	V _{OH}		+25°C		65	95	mV
			Full			130	
	V _{OL}		+25°C		37	60	
			Full			85	
Output Short-Circuit Current	I _{SC}		+25°C		±17		mA
Power Supply							
Operating Voltage Range	V _S		Full	3		24	V
Quiescent Current/Amplifier	I _Q	I _{OUT} = 0mA	+25°C		50	64	μA
			Full			84	
Power Supply Rejection Ratio	PSRR	V _S = 3V to 24V	+25°C	116	142		dB
			Full	113			
Dynamic Performance							
Gain-Bandwidth Product	GBP	G = +100, C _L = 100pF	+25°C		350		kHz
Slew Rate	SR	G = +1, V _{OUT} = 2V _{P,P} , C _L = 100pF	+25°C		0.09		V/μs
Turn-On Time			+25°C		1.5		ms
Noise							
Input Voltage Noise		f = 0.1Hz to 10Hz	+25°C		0.85		μV _{P,P}
Input Voltage Noise Density	e _n	f = 1kHz	+25°C		40		nV/√Hz

TYPICAL PERFORMANCE CHARACTERISTICS

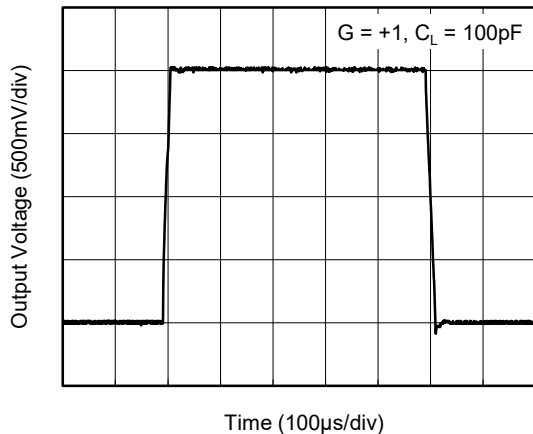
At $T_A = +25^\circ\text{C}$, $+V_S = 5\text{V}$, $-V_S = 0\text{V}$, $R_L = 10\text{k}\Omega$ and $C_L = 0\text{pF}$, unless otherwise noted.



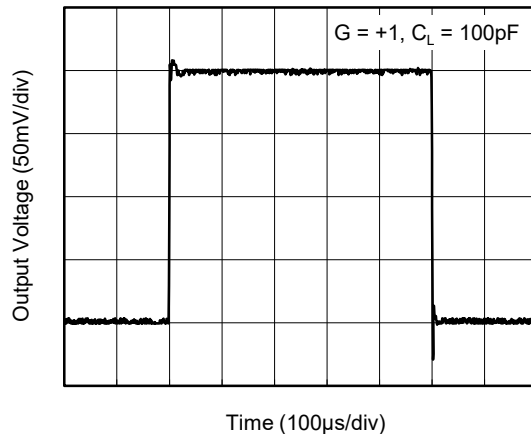
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $+V_S = 5\text{V}$, $-V_S = 0\text{V}$, $R_L = 10\text{k}\Omega$ and $C_L = 0\text{pF}$, unless otherwise noted.

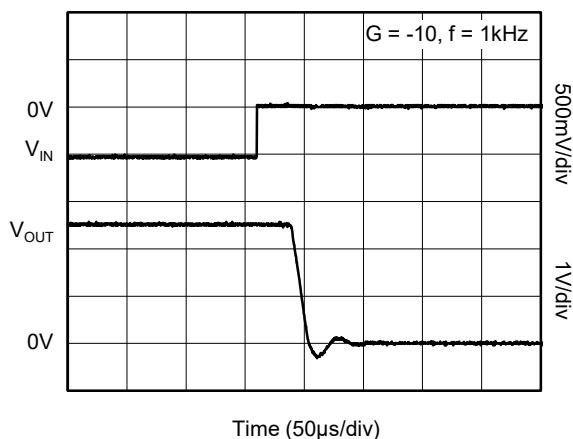
Large-Signal Step Response



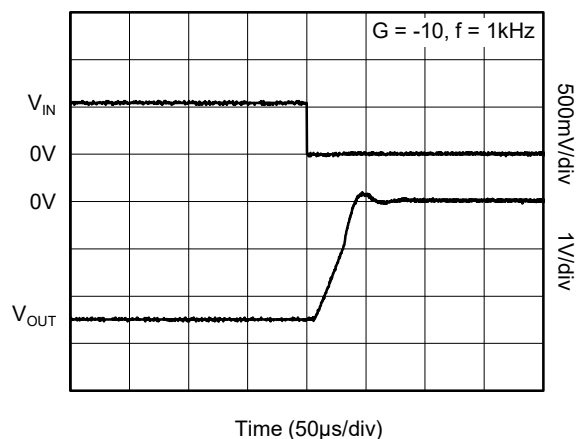
Small-Signal Step Response



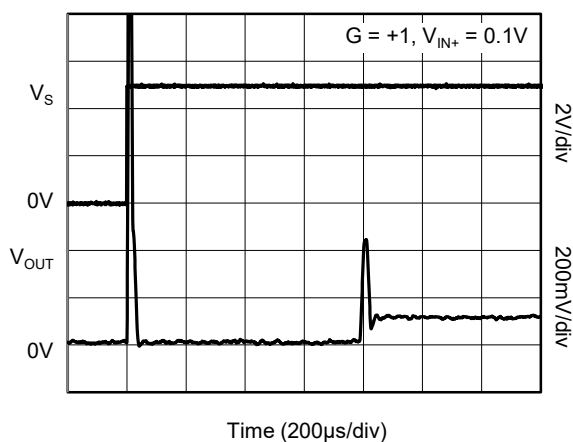
Positive Overload Recovery



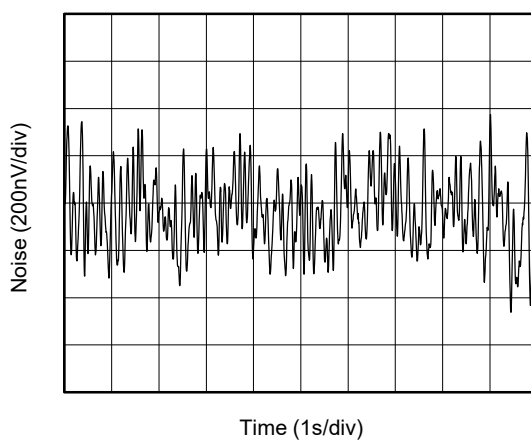
Negative Overload Recovery



Turn-On Time

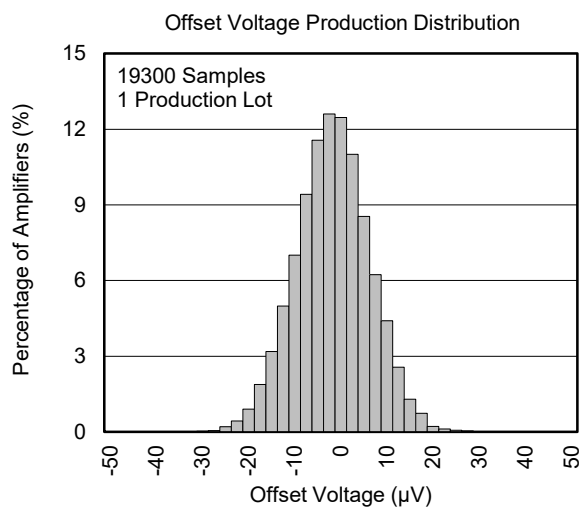
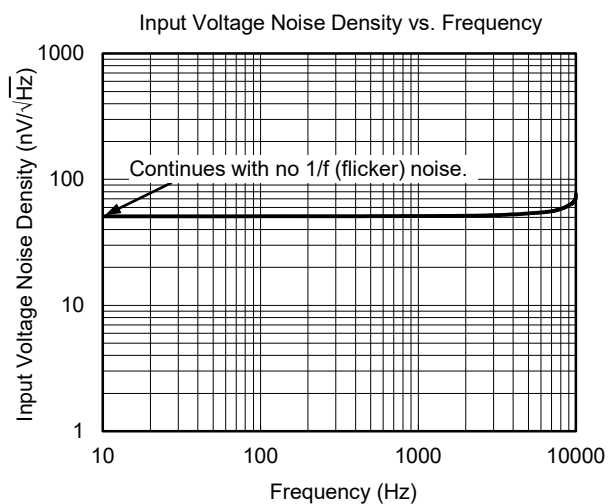


0.1Hz to 10Hz Noise



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

At $T_A = +25^\circ\text{C}$, $+V_S = 5\text{V}$, $-V_S = 0\text{V}$, $R_L = 10\text{k}\Omega$ and $C_L = 0\text{pF}$, unless otherwise noted.



APPLICATION INFORMATION

Rail-to-Rail Input

When SGM8250-1/2 work at the power supply between 3V and 24V, the input common mode voltage range is from $(-V_S) - 0.1V$ to $(+V_S) + 0.1V$. In Figure 1, the ESD diodes between the inputs and the power supply rails will clamp the input voltage not to exceed the rails.

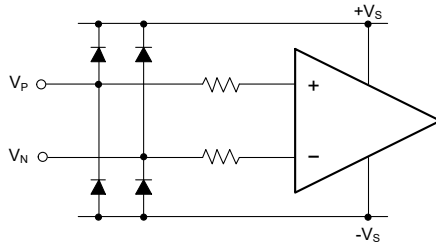


Figure 1. Input Equivalent Circuit

Input Current-Limit Protection

For ESD diode clamping protection, when the current flowing through ESD diode exceeds the maximum rating value, the ESD diode and amplifier will be damaged, so current-limit protection will be added in some applications. One resistor is selected to limit the current not to exceed the maximum rating value. In Figure 2, a series input resistor is used to limit the input current to less than 10mA, but the drawback of this current-limit resistor is that it contributes thermal noise at the amplifier input. If this resistor must be added, its value must be selected as small as possible.

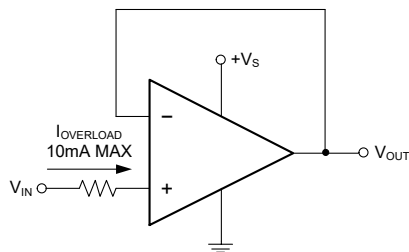


Figure 2. Input Current-Limit Protection

Rail-to-Rail Output

The SGM8250-1/2 support rail-to-rail output operation. In single power supply application, for example, when $+V_S = 24V$, $-V_S = GND$, 10k Ω load resistor is tied from OUT pin to $+V_S/2$, the typical output swing range is from 0.037V to 23.935V.

Driving Capacitive Loads

The SGM8250-1/2 are designed for driving capacitive load with unity-gain stable. If greater capacitive load must be driven in application, the circuit in Figure 3 can be used. In this circuit, the IR drop voltage generated by R_{ISO} is compensated by feedback loop.

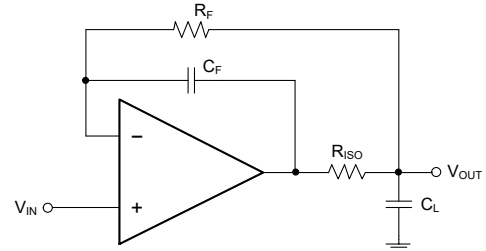


Figure 3. Circuit to Drive Heavy Capacitive Load

Power Supply Decoupling and Layout

A clean and low noise power supply is very important in amplifier circuit design, besides of input signal noise, the power supply is one of important source of noise to the amplifiers through $+V_S$ and $-V_S$ pins. Power supply bypassing is an effective method to clear up the noise at power supply, and the low impedance path to ground of decoupling capacitor will bypass the noise to GND. In application, 10 μF ceramic capacitor paralleled with 0.1 μF or 0.01 μF ceramic capacitor is used in Figure 4. The ceramic capacitors should be placed as close as possible to $+V_S$ and $-V_S$ power supply pins.

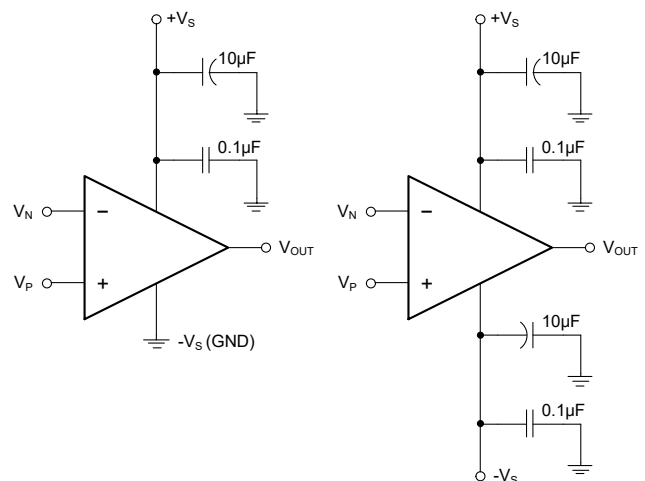


Figure 4. Amplifier Power Supply Bypassing

APPLICATION INFORMATION (continued)

Grounding

In low speed application, one node grounding technique is the simplest and most effective method to eliminate the noise generated by grounding. In high speed application, the general method to eliminate noise is to use a complete ground plane technique, and the whole ground plane will help distribute heat and reduce EMI noise pickup.

Reduce Input-to-Output Coupling

To reduce the input-to-output coupling, the input traces must be placed as far away from the power supply or output traces as possible. The sensitive trace must not be placed in parallel with the noisy trace in same layer. They must be placed perpendicularly in different layers to reduce the crosstalk. These PCB layout techniques will help to reduce unwanted positive feedback and noise.

Typical Application Circuits

Difference Amplifier

The circuit in Figure 5 is a design example of classical difference amplifier. If $R_4/R_3 = R_2/R_1$, then $V_{OUT} = (V_P - V_N) \times R_2/R_1 + V_{REF}$.

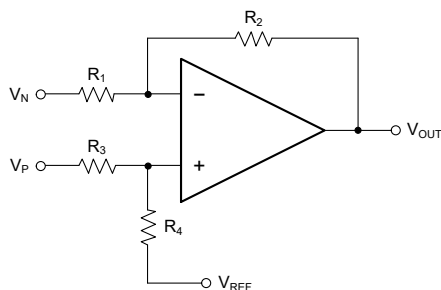


Figure 5. Difference Amplifier

High Input Impedance Difference Amplifier

The circuit in Figure 6 is a design example of high input impedance difference amplifier, the added amplifiers at

the input are used to increase the input impedance and eliminate drawback of low input impedance in Figure 5.

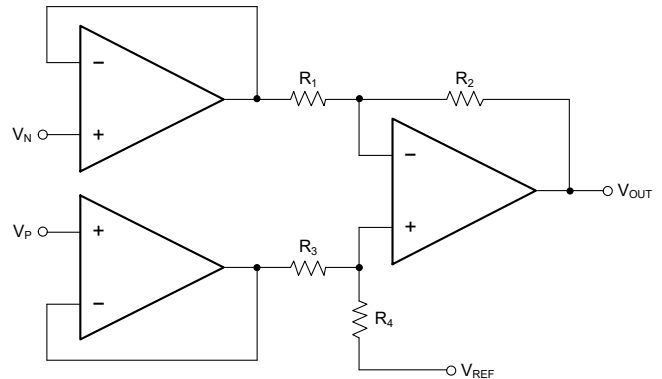


Figure 6. High Input Impedance Difference Amplifier

Active Low-Pass Filter

The circuit in Figure 7 is a design example of active low-pass filter, the DC gain is equal to $-R_2/R_1$ and the -3dB corner frequency is equal to $1/2\pi R_2 C$. In this design, the filter bandwidth must be less than the bandwidth of the amplifier, the resistor values must be selected as low as possible to reduce ringing or oscillation generated by the parasitic parameters in PCB layout.

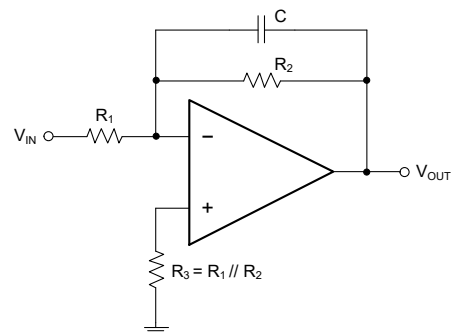


Figure 7. Active Low-Pass Filter

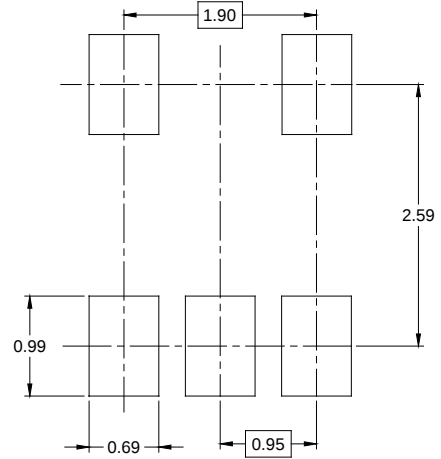
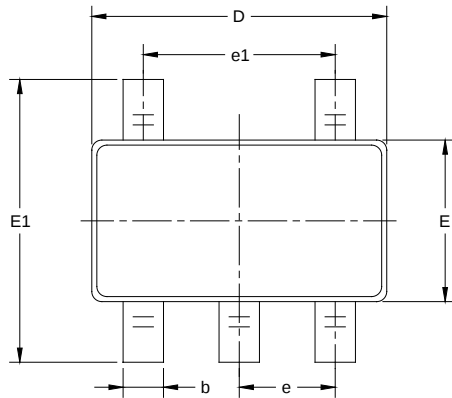
REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

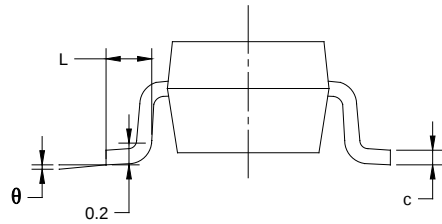
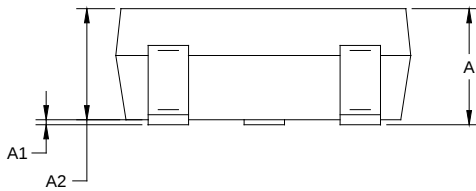
JULY 2023 – REV.A to REV.A.1		Page
Updated Package Outline Dimensions section		13
Changes from Original (DECEMBER 2017) to REV.A		Page
Changed from product preview to production data.....		All

PACKAGE OUTLINE DIMENSIONS

SOT-23-5



RECOMMENDED LAND PATTERN (Unit: mm)



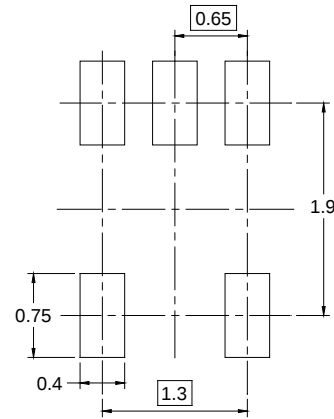
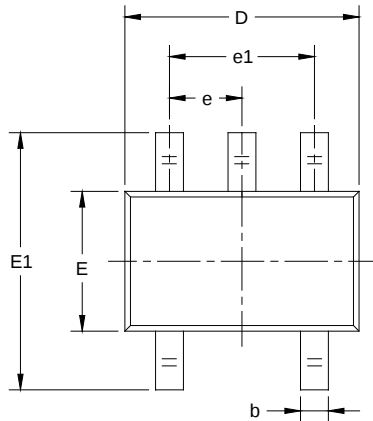
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950 BSC		0.037 BSC	
e1	1.900 BSC		0.075 BSC	
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

NOTES:

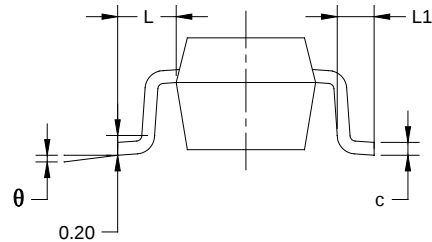
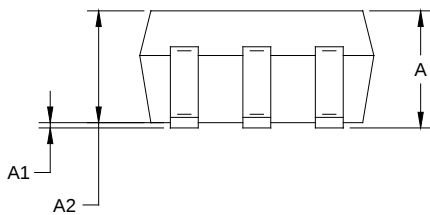
1. Body dimensions do not include mold flash or protrusion.
2. This drawing is subject to change without notice.

PACKAGE OUTLINE DIMENSIONS

SC70-5



RECOMMENDED LAND PATTERN (Unit: mm)



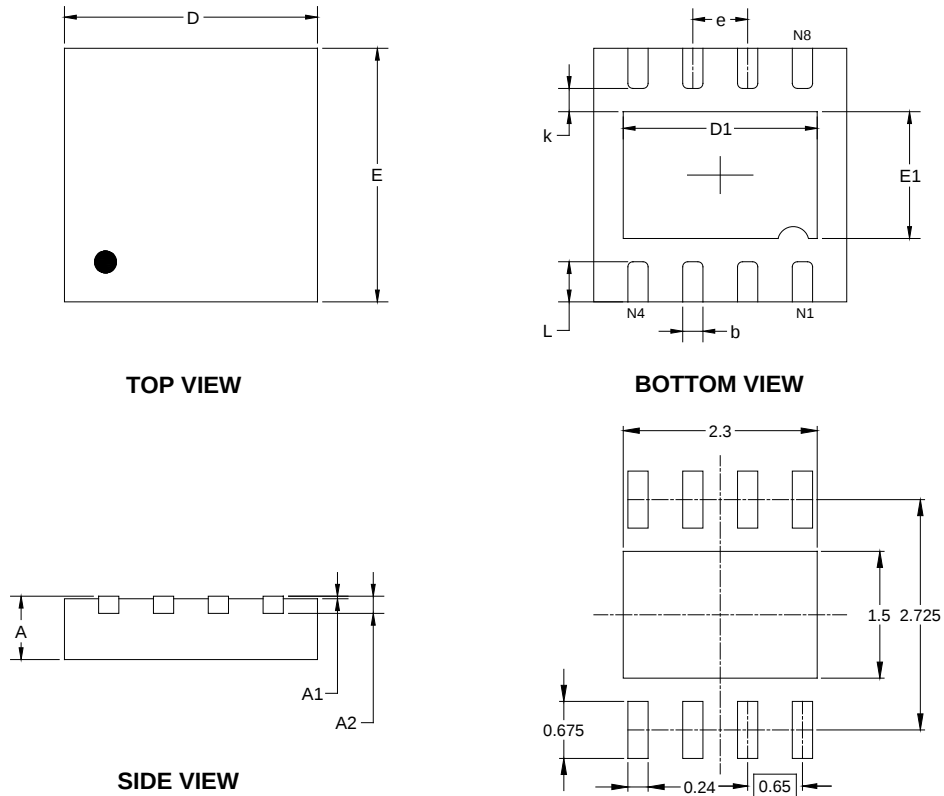
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.800	1.100	0.031	0.043
A1	0.000	0.100	0.000	0.004
A2	0.800	1.000	0.031	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.220	0.003	0.009
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.65 TYP		0.026 TYP	
e1	1.300 BSC		0.051 BSC	
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

NOTES:

1. Body dimensions do not include mold flash or protrusion.
2. This drawing is subject to change without notice.

PACKAGE OUTLINE DIMENSIONS

TDFN-3×3-8L



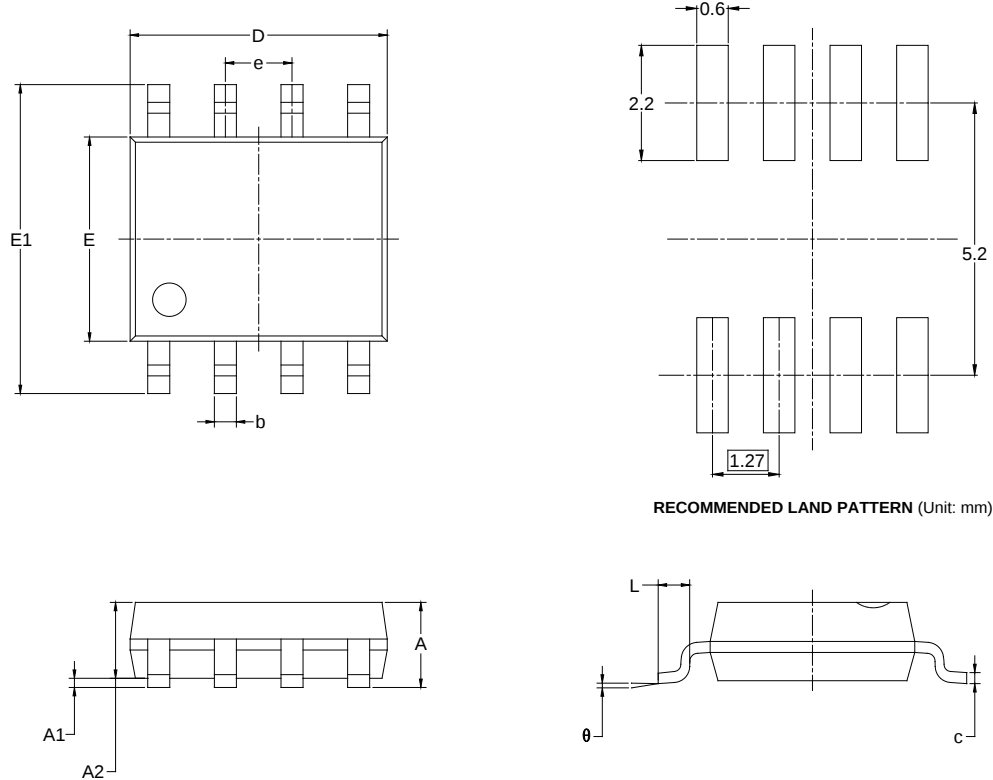
RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A2	0.203 REF		0.008 REF	
D	2.900	3.100	0.114	0.122
D1	2.200	2.400	0.087	0.094
E	2.900	3.100	0.114	0.122
E1	1.400	1.600	0.055	0.063
k	0.200 MIN		0.008 MIN	
b	0.180	0.300	0.007	0.012
e	0.650 TYP		0.026 TYP	
L	0.375	0.575	0.015	0.023

NOTE: This drawing is subject to change without notice.

PACKAGE OUTLINE DIMENSIONS

SOIC-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

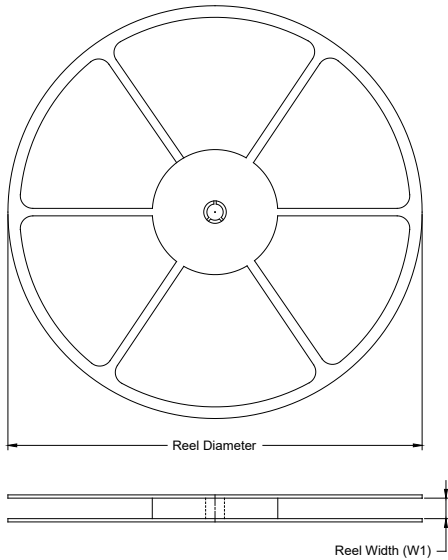
NOTES:

1. Body dimensions do not include mold flash or protrusion.
2. This drawing is subject to change without notice.

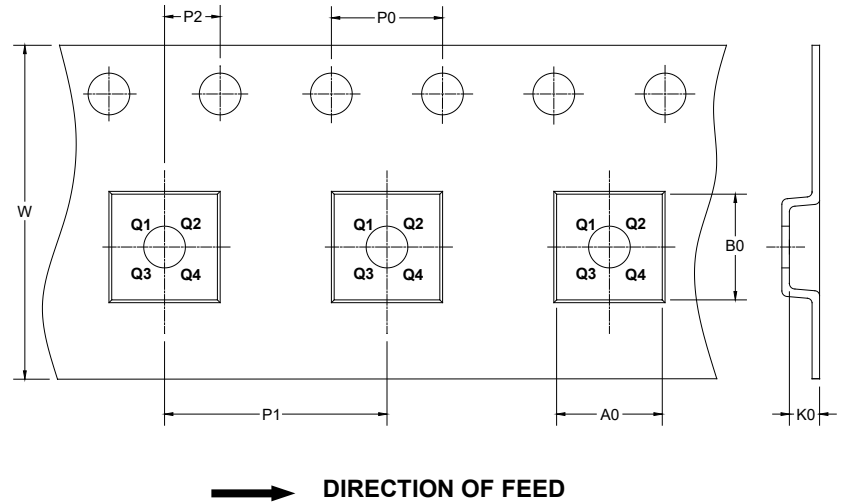
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT-23-5	7"	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3
SC70-5	7"	9.5	2.40	2.50	1.20	4.0	4.0	2.0	8.0	Q3
TDFN-3×3-8L	13"	12.4	3.35	3.35	1.13	4.0	8.0	2.0	12.0	Q1
SOIC-8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1

DD0001

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18
13"	386	280	370	5

DD0002